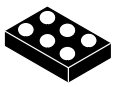
28 V / 4 A Rated OVP with Low On-resistance

FPF2286UCX



WLCSP6
CASE 567UV

FPF2286 is an OVP with integrated low on-resistance single channel switch. The device contains an N-MOSFET that can operate over an input voltage range of 2.8 V to 23 V and can support a maximum continuous current of 4 A.

When the input voltage exceeds the over-voltage threshold, the internal FET is turned off immediately to prevent damage to the protected downstream components.

FPF2286 is available in a small 6-bump WLCSP package and operate over the free-air temperature range of −40 °C to +85 °C.

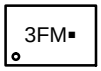
Features

- Over-voltage Protection Up to +28 V
- Internal Low $R_{DS(on)}$ NMOS Transistors: Typical 25 mΩ
- Programmable Over-voltage Lockout (OVLO)
  - Externally Adjustable via OVLO Pin
- Active-low Enable Pin (OVLO) for Device
- Super Fast OVLO Response Time: Typical 40 ns
- Short Circuit Protection and Auto-restart
- Over Temperature Protection (Thermal Shutdown)
- Robust ESD Performance
  - 2 kV Human Body Model (HBM)
  - 1 kV Charged Device Model (CDM)
  - V_{IN} Tolerant to 35 V Residue-voltage during Surge Event
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

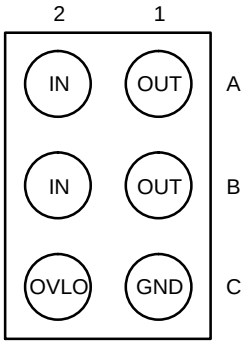
- Mobile Phones
- PDAs
- GPS

MARKING DIAGRAM



3F = Specific Device Code
M = Month Code
▪ = Pb-Free Package

PIN CONNECTIONS



(Bottom View)

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

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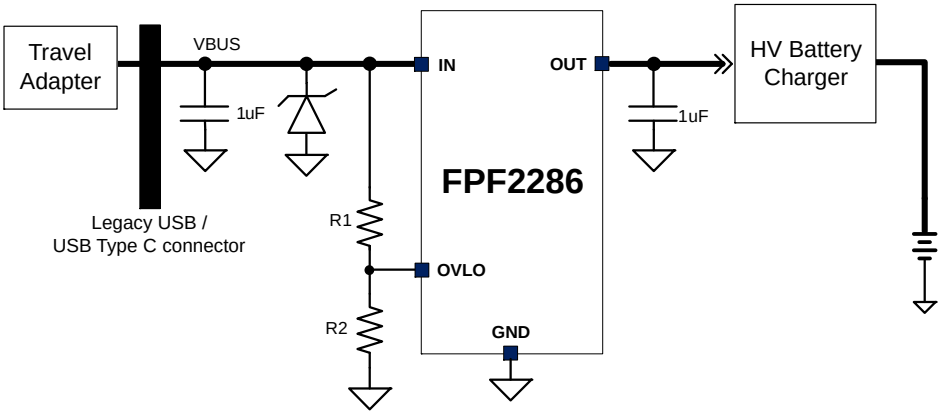


Figure 1. Application Schematic − Adjustable Option

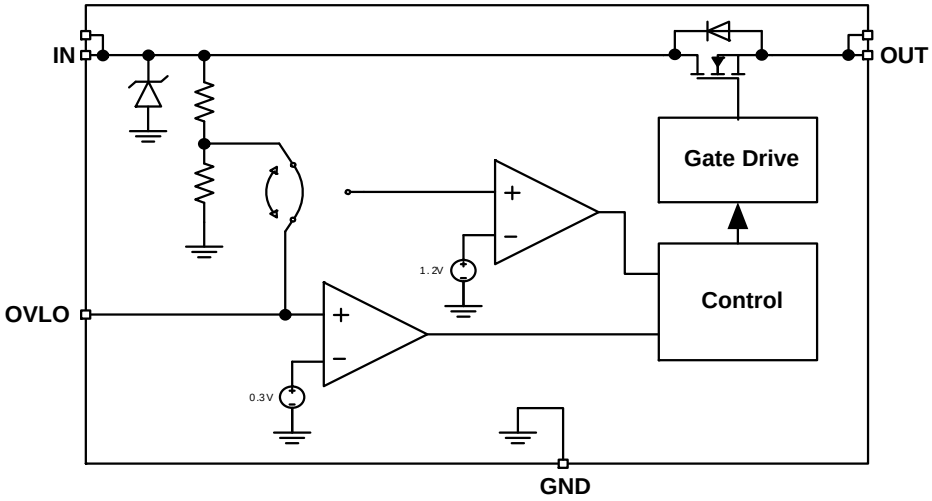


Figure 2. Simplified Block Diagram

Table 1. PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
A2, B2	IN	Power Input: Switch Input and Device Supply
A1, B1	OUT	Power Output: Switch Output to Load
C2	OVLO	OVLO Input: Over Voltage Lockout Adjustment Input
C1	GND	Ground

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Table 2. MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage Range (Note 1)	V_{in}	−0.3 to 28	V
Output Voltage Range	V_{out}	−0.3 to (V_{in} + 0.3)	V
Adjustable Input Range	V_{OVLO}	−0.3 to 23	V
Internal FET continuous current	I_{OUT}	0 to 4	A
Maximum Junction Temperature	$T_{J(max)}$	150	°C
Storage Temperature Range	T_{STG}	−65 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD_{HBM}	2	kV
ESD Capability, Charged Device Model (Note 2)	ESD_{CDM}	1	kV
Lead Temperature Soldering Reflow (SMD Styles Only), Pb-Free Versions (Note 3)	T_{SLD}	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.
2. This device series incorporates ESD protection and is tested by the following methods:
   ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
   ESD Charged Device Model tested per AEC-Q100-011 (EIA/JESD22-C101)
   Latch-up Current Maximum Rating: ≤150 mA per JEDEC standard: JESD78
3. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Table 3. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, WLCSP-6 (Note 4) Thermal Resistance, Junction-to-Air (Note 5)	$R_{\theta JA}$	121.7	°C/W

4. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.
5. Values based on 2S2P JEDEC std. PCB.

Table 4. RECOMMENDED OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Supply Voltage on VIN	V_{in}	2.8	23	V
I/O pins	V_{OVLO}	0	5.5	V
Output Current	I_{out}	0	3.5	A
IN Capacitor	C_{in}	0.1		µF
OUT Capacitor	C_{out}	0.1		µF
Ambient Temperature	T_A	−40	85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

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Table 5. ELECTRICAL CHARACTERISTICS
V_{IN} = 2.8 to 23 V, C_{IN} = 0.1 μF, C_{OUT} = 0.1 μF, T_A = −40 to 85 °C; For typical values V_{IN} = 5.0 V, I_{IN} ≤ 3 A, C_{IN} = 0.1 μF, T_A = 25 °C, for min/max values T_A = −40 °C to 85 °C; unless otherwise noted. (Note 6)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
LEAKAGE AND QUIESCENT CURRENTS						
Input Quiescent Current on VIN	V_{IN} = 5 V, V_{OVLO} = 0.6 V	I_Q		85		μA
	V_{IN} = 20 V, V_{OVLO} = 0.6 V			200		
Supply Current during Over Voltage	V_{IN} = 23 V, V_{OVLO} = 3.0 V, V_{OUT} = 0 V	I_{IN_Q}		215		μA
OVLO Input Leakage Current	V_{OVLO} = V_{OVLO_TH}	I_{OVLO}	−100		100	nA
OVER VOLTAGE AND UNDER VOLTAGE LOCKOUT						
Under-Voltage Rising Trip Level for VIN	V_{IN} rising, T_A = −40 to 85 °C	$V_{IN_UV_R}$	2.3	2.5	2.7	V
Under-Voltage Falling Trip Level for VIN	V_{IN} falling, T_A = −40 to 85 °C	$V_{IN_UV_F}$		2.4		V
Default Over-Voltage Trip Level	V_{IN} rising, T_A = −40 to 85 °C	V_{IN_OVLO}	6.6	6.8	7.0	V
OVLO set threshold	V_{OVLO} = 1.1 V to 1.3 V, the voltage of OVLO to trigger Over Voltage condition	V_{OVLO_TH}	1.16	1.19	1.22	V
OVLO threshold hysteresis		V_{HYS_OVLO}		2		%
Adjustable OVLO range	OV_MODE = 0, V_{OVLO} > 0.5 V	V_{OV_RNG}	4		23	V
I/O THRESHOLDS						
OVLO Input Threshold Voltage						V
Voltage Increasing, Logic High	High	V_{IH_OVLO}	0.3	–	–	
Voltage Decreasing, Logic Low	Low	V_{IL_OVLO}	–	–	0.15	
RESISTANCE						
On-resistance of Power FET	V_{IN} = 5 V, I_{OUT} = 500 mA, T_A = 25 °C	r_{ON}		25	35	mΩ
TIMING						
De-bounce Time of Power FET turned on	Time from 2.5 V < V_{IN} < V_{IN_OVLO} to V_{OUT} = 0.1 × V_{IN}	t_{SW_DEB}		15		ms
Switch Turn-On rising Time (Note 8)	V_{IN} = 5 V, R_L = 100 Ω, C_L = 22 μF, V_{OUT} from 0.1 × V_{IN} to 0.9 × V_{IN}	t_R		1		ms
Switch Turn-Off Time (Note 8)	R_L = 10 Ω, C_L = 0 μF, time from V_{IN} > V_{OVLO} to V_{OUT} = 0.9 × V_{IN}					ns
	Internal OVP level			40		
	External OVP level (Note 9)			100		
THERMAL SHUTDOWN						
Thermal Shutdown Temperature (Note 8)		T_{SD}	–	130	–	°C
Thermal Shutdown Hysteresis (Note 8)		T_{SH}	–	20	–	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. Performance guaranteed over the indicated operating temperature range by design and/or characterization tested at T_J = T_A = 25 °C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
7. Refer to the APPLICATION INFORMATION section.
8. Values based on design and/or characterization.
9. Depends on the capacitance on OVLO pin.

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Function Description

General

FPF2286 is an OVP power switch to protect next stage system which is optimized to lower voltage working condition. The device includes ultra low on-resistance power FET (25 mΩ) and super fast OVP response time (40 ns).

Power MOSFET

The FPF2286 integrates an N-type MOSFET with 25 mΩ resistance. The power FET can work under 2.8 V ~ 23 V and up to 4 A DC current capability.

Power Supply

The FPF2286 is supplied by IN. IN will be firstly supplied by OUT when the device is working under USB On-The-Go (OTG) condition.

Enable Control

There is no specified enable pin for FPF2286. However, the OVLO can be used as an active LOW enable pin to be controlled by a GPIO. When OVLO pin is connected to a high level (higher than 1.2 V), the internal FET will be turned off. When OVLO pin is connected to 0 V, the FET will be turned on as long as V_{IN} is not higher than 6.8 V.

Under Voltage Lockout

FPF2286 power switch will be turned off when the voltage on IN is lower than the UVLO threshold $V_{IN_UV_F}$.

Whenever VIN voltage ramps up to higher than $V_{IN_UV_R}$, the power FET will be turned on automatically after t_{DEB} de-bounce time if there is no OV or OT condition.

Over Voltage Lockout

The power FET will be turned off whenever VIN voltage higher than V_{IN_OVLO}. The value of V_{IN_OVLO} can be set by external resistor ladder or just be default value V_{IN_OVLO}.

When V_{OVLO} is smaller than V_{IL_OVLO}, V_{OVLO} will be decided by default value. When V_{OVLO} is larger than V_{IH_OVLO}, the power switch will be turned off once $V_{OVLO} > V_{OVLO_TH}$. The external resistor ladder can be decided according to the following equation:

$$V_{IN_OVLO} = V_{OVLO_TH} \times (1 + R1/R2) \quad \text{(eq. 1)}$$

where R1 and R2 are the resistors in Figure 1.

Thermal Shutdown

When the device is in the switch mode, to protect the device from over temperature, the power switch will be turned off when the junction temperature exceeds T_{SD}. The switch will be turned on again when temperature drop below $T_{SD} - T_{SH}$.

APPLICATIONS INFORMATION

Input Decoupling (C_{in})

A ceramic or tantalum at least 0.1 μF capacitor is recommended and should be connected close to the FPF2286 package. Higher capacitance and lower ESR will improve the overall line and load transient response.

Output Decoupling (C_{out})

The FPF2286 is a stable component and does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The minimum output decoupling value is 0.1 μF and can be augmented to fulfill stringent load transient requirements.

Thermal Considerations

As power in the FPF2286 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. When the FPF2286 has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power applications. The maximum dissipation the FPF2286 can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_A\right]}{R_{\theta JA}} \quad \text{(eq. 2)}$$

Since T_J is not recommended to exceed 125 °C, then the FPF2286 soldered on 645 mm^2, 1 oz copper area, and the ambient temperature (T_A) is 25 °C. The power dissipated by the FPF2286 can be calculated from the following equations:

$$P_D \approx V_{in} \cdot \left(I_Q @ I_{out}\right) + {I_{out}}^2 \cdot r_{ON} \quad \text{(eq. 3)}$$

Hints

V_{in} and V_{out} printed circuit board traces should be as wide as possible. Place external components, especially the input capacitor and TVS, as close as possible to the FPF2286, and make traces as short as possible.

ORDERING INFORMATION

Device	Default OV Level	Marking	Package	Shipping†
FPF2286UCX	6.8 V	3F	WLCSP-6L	3000 / Tape & Reel

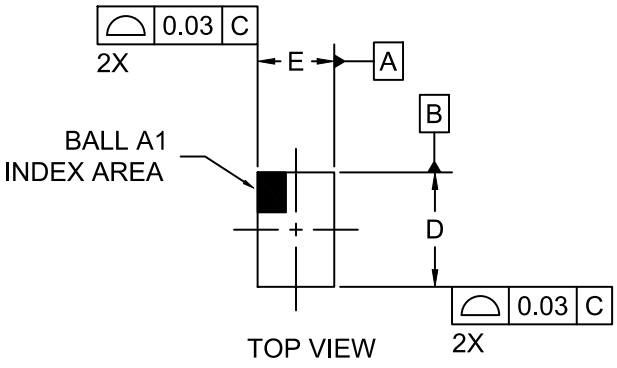
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

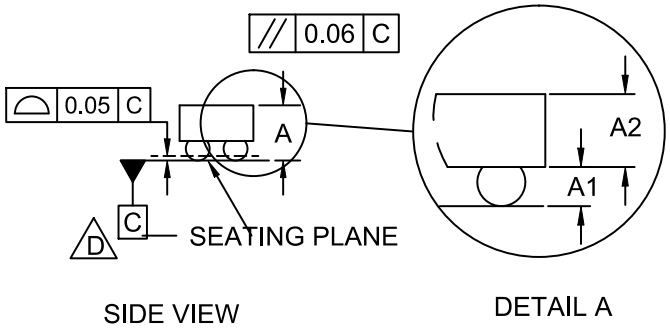
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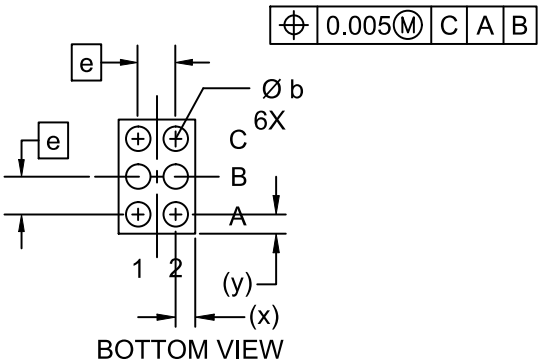
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CASE 567UV
ISSUE O

DATE 05 JUL 2017



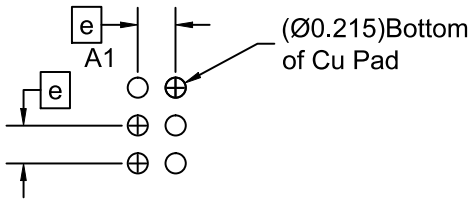




NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DATUM C APPLIES TO THE SPHERICAL CROWN OF THE SOLDER BALLS

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.536	0.574	0.612
A1	0.176	0.196	0.216
A2	0.360	0.378	0.396
b	0.240	0.260	0.280
D	1.270	1.300	1.330
E	0.870	0.900	0.930
e	0.40 BSC		
x	0.235	0.250	0.265
y	0.235	0.250	0.265



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